

Fast IGBT4 Modules

SKM75GB12T4

Features

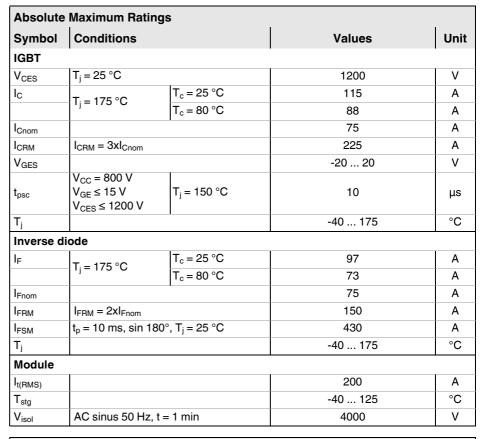
- IGBT4 = 4. generation fast trench IGBT (Infineon)
- CAL4 = Soft switching 4. generation CAL-diode
- Insulated copper baseplate using DBC technology (Direct Bonded Copper)
- · Increased power cycling capability
- With integrated gate resistor
- For higher switching frequencies up to 20kHz
- UL recognized, file no. E63532

Typical Applications*

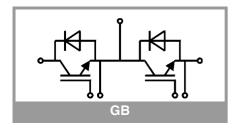
- AC inverter drives
- UPS
- · Electronic welders at fsw up to 20 kHz

Remarks

- Case temperature limited to T_c = 125°C max.
- Recommended T_{op} = -40 ... +150°C
- Product reliability results valid for T_j = 150°C



Characte	eristics					
Symbol	Conditions	min.	typ.	max.	Unit	
IGBT						•
V _{CE(sat)}	$I_C = 75 \text{ A}$ $V_{GE} = 15 \text{ V}$ chiplevel	T _j = 25 °C		1.85	2.10	V
		T _j = 150 °C		2.28	2.45	V
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V
		T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		14	16	mΩ
		T _j = 150 °C		21	22	mΩ
$V_{GE(th)}$	$V_{GE}=V_{CE}$, $I_{C}=3$ mA		5	5.8	6.5	٧
I _{CES}	V _{GE} = 0 V V _{CE} = 1200 V	T _j = 25 °C			1	mA
		T _j = 150 °C		-		mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		4.4		nF
Coes		f = 1 MHz		0.29		nF
C _{res}		f = 1 MHz		0.24		nF
Q _G	V _{GE} = - 8 V+ 15 V			425		nC
R _{Gint}	T _j = 25 °C			10		Ω
t _{d(on)}	$\begin{array}{c} V_{CC} = 600 \ V \\ I_{C} = 75 \ A \\ V_{GE} = +15/-15 \ V \\ R_{G \ on} = 1 \ \Omega \\ R_{G \ off} = 1 \ \Omega \\ di/dt_{on} = 1600 \ A/\mu s \\ di/dt_{off} = 950 \ A/\mu s \end{array}$	T _j = 150 °C		150		ns
t _r		T _j = 150 °C		39		ns
Eon		T _j = 150 °C		11		mJ
t _{d(off)}		T _j = 150 °C		370		ns
t _f		T _j = 150 °C		66		ns
E _{off}		T _j = 150 °C		6.9		mJ
R _{th(j-c)}	per IGBT			0.38	K/W	





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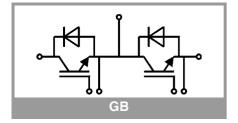
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Characteristics										
Symbol	Conditions	min.	typ.	max.	Unit					
Inverse diode										
$V_{GE} = 0$	I _F = 75 A	T _j = 25 °C		2.17	2.49	V				
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.11	2.42	V				
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V				
		T _j = 150 °C		0.90	1.10	V				
r _F	chiplevel	T _j = 25 °C		12	13	mΩ				
		T _j = 150 °C		16	18	mΩ				
I _{RRM}	$\begin{array}{l} I_F = 75 \text{ A} \\ di/dt_{off} = 990 \text{ A/}\mu\text{s} \\ V_{GE} = \pm 15 \text{ V} \\ V_{CC} = 600 \text{ V} \end{array}$	T _j = 150 °C		37		Α				
Q _{rr}		T _j = 150 °C		12.6		μC				
E _{rr}		T _j = 150 °C		4.7		mJ				
R _{th(j-c)}	per diode				0.58	K/W				
Module										
L _{CE}				30		nH				
R _{CC'+EE'}	measured per switch	T _C = 25 °C		0.65		mΩ				
		T _C = 125 °C		1.09		mΩ				
R _{th(c-s)}	calculated without thermal coupling (λ _{grease} =0.81 W/(m*K))			0.04	0.05	K/W				
Ms	to heat sink M6		3		5	Nm				
Mt		to terminals M5	2.5		5	Nm				
						Nm				
w					160	g				



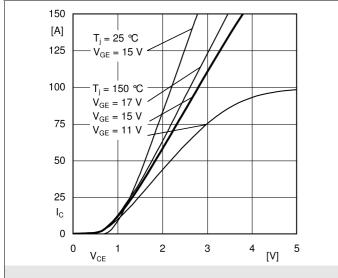


Fig. 1: Typ. output characteristic, inclusive R_{CC'+ EE'}

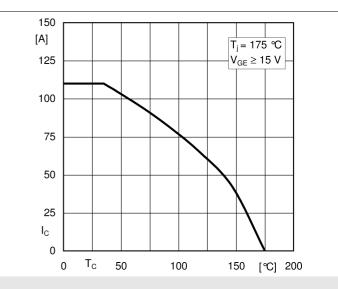


Fig. 2: Rated current vs. temperature $I_C = f(T_C)$

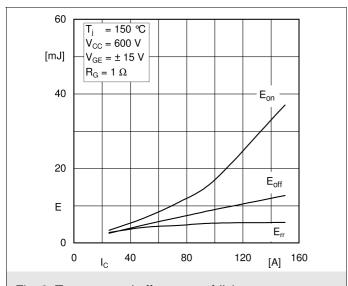


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

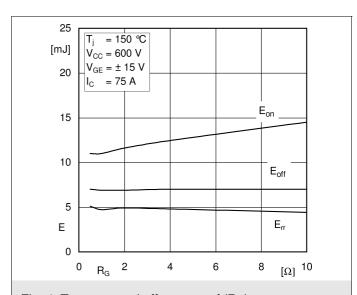


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

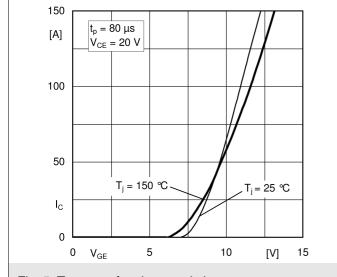


Fig. 5: Typ. transfer characteristic

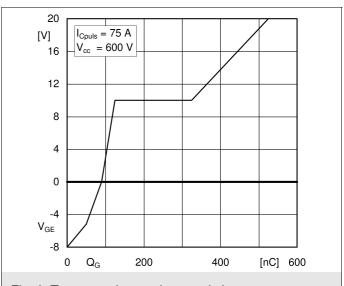
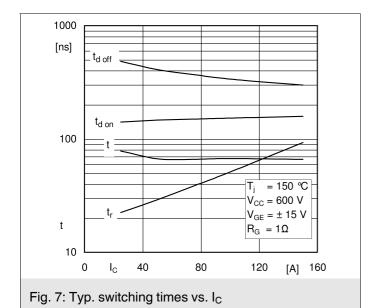
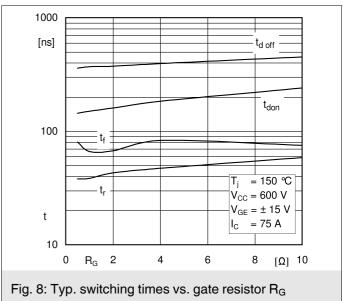
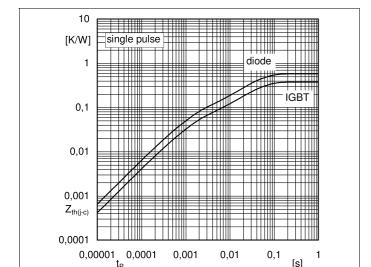


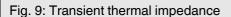
Fig. 6: Typ. gate charge characteristic







[s]



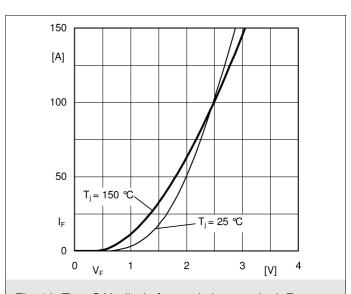


Fig. 10: Typ. CAL diode forward charact., incl. R_{CC'+ EE'}

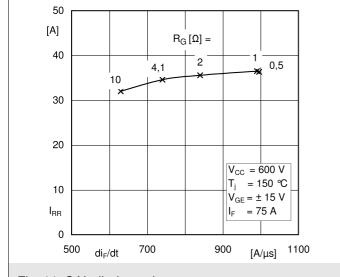


Fig. 11: CAL diode peak reverse recovery current

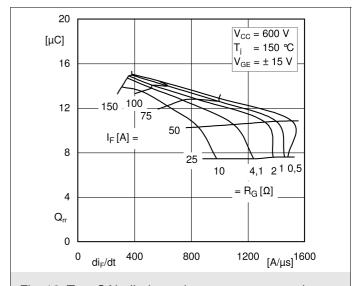
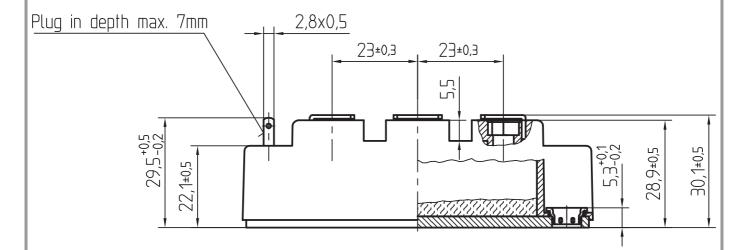
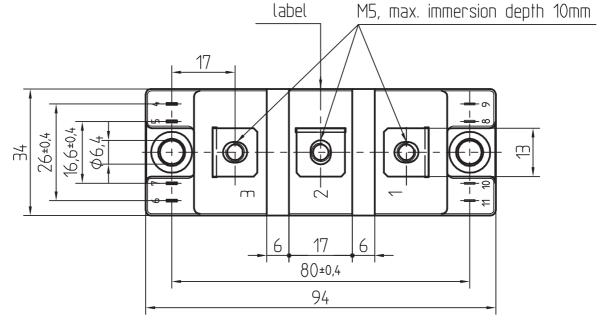


Fig. 12: Typ. CAL diode peak reverse recovery charge

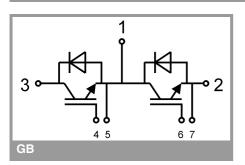






General tolerance +/- 0,5 mm

SEMITRANS 2



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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